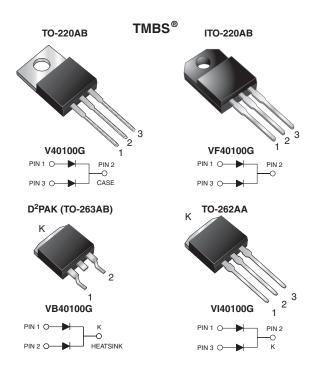
V40100G-E3, VF40100G-E3, VB40100G-E3, VI40100G-E3

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Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.42 \text{ V}$ at $I_F = 5 \text{ A}$



DESIGN SUPPORT TOOLS





PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 20 A					
V_{RRM}	100 V					
I _{FSM}	200 A					
V _F at I _F = 20 A	0.67 V					
T _J max.	150 °C					
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- · Low thermal resistance



- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICALDATA

Case: TO-220AB, ITO-220AB, D^2PAK (TO-263AB) and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER	SYMBOI	V40100G	VF40100G	VB40100G	VI40100G	UNIT		
Maximum repetitive peak reverse voltage	V_{RRM}	100				V		
Maximum average forward rectified current per de		40			A			
(fig. 1) per di	ode I _{F(AV)}	20						
Peak forward surge current 8.3 ms single half sine-wave superimpon rated load per diode	l _{FSM}	200				Α		
Non-repetitive avalanche energy at $T_J = 25$ °C, $L = 90$ mH per dic	ode E _{AS}	230			mJ			
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C per diode		1.0		Α				
Voltage rate of change (rated V _R)	dV/dt	10 000		V/µs				
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1	min V _{AC}	1500		V				
Operating junction and storage temperature range	T _J , T _{STG}	-40 to +150			°C			

V40100G-E3, VF40100G-E3, VB40100G-E3, VI40100G-E3

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL TYP.		MAX.	UNIT		
Breakdown voltage	I _R = 1.0 mA	T _A = 25 °C	V_{BR}	100 min.	-			
Instantaneous forward voltage per diode ⁽¹⁾	I _F = 5 A		- V _F	0.49	-			
	I _F = 10 A	T _A = 25 °C		0.59	-	T .,		
	I _F = 20 A]		0.75	0.81	V		
	I _F = 5 A	T _A = 125 °C		0.42	-			
	I _F = 10 A			0.54	-			
	I _F = 20 A]		0.67	0.73			
Reverse current per diode (2)	V _R = 70 V	T _A = 25 °C		12	-	μA		
	v _R = 70 v	T _A = 125 °C		8	-	mA		
	V _R = 100 V	T _A = 25 °C	I _R	55	500	μA		
	V _R = 100 V	T _A = 125 °C		21	35	mA		

Notes

 $^{(1)}\,\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V40100G	VF40100G	VB40100G	VI40100G	UNIT	
Typical thermal resistance per diode	$R_{\theta JC}$	2.0	5.0	2.0	2.0	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V40100G-E3/4W	1.88	4W	50/tube	Tube			
ITO-220AB	VF40100G-E3/4W	1.75	4W	50/tube	Tube			
TO-263AB	VB40100G-E3/4W	1.39	4W	50/tube	Tube			
TO-263AB	VB40100G-E3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VI40100G-E3/4W	1.46	4W	50/tube	Tube			

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

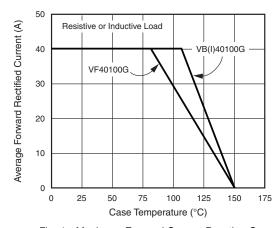


Fig. 1 - Maximum Forward Current Derating Curve

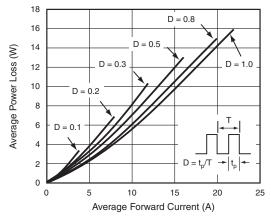


Fig. 2 - Forward Power Loss Characteristics

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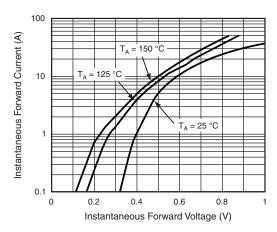


Fig. 3 - Typical Instantaneous Forward Characteristics

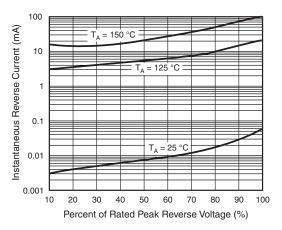


Fig. 4 - Typical Reverse Characteristics

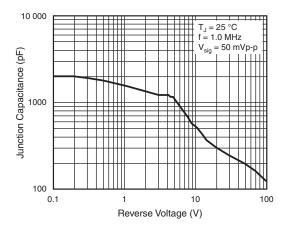


Fig. 5 - Typical Junction Capacitance

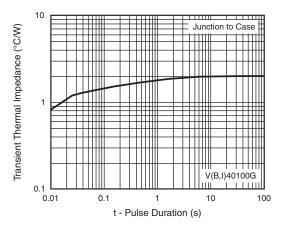


Fig. 6 - Typical Transient Thermal Impedance

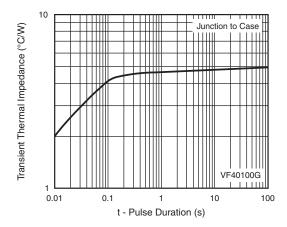


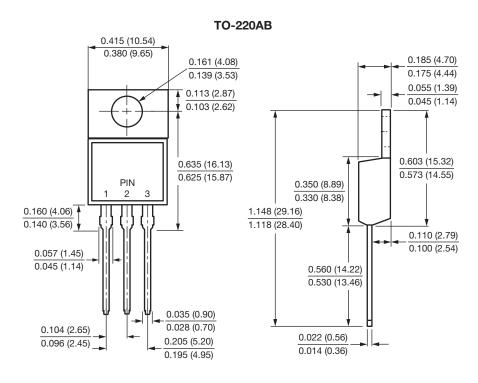
Fig. 7 - Typical Transient Thermal Impedance

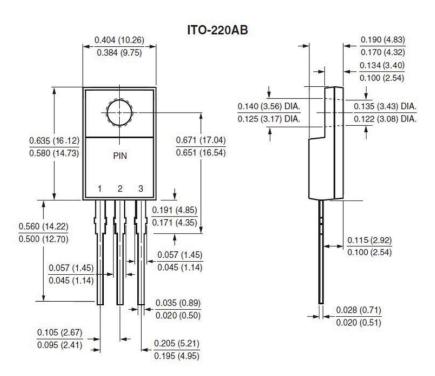


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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

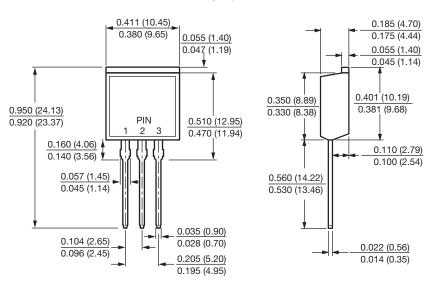




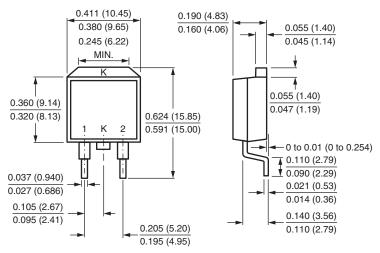
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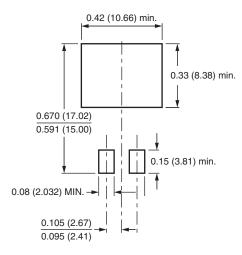
TO-262AA



D²PAK (TO-263AB)



Mounting Pad Layout





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